Symbol	mbol Parameter Test Conditions		Min	Тур	Max	Unit
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> = 0V		420		
C <sub>oss</sub> Output Capacitance		V <sub>DS</sub> = 50V		210		pF
C <sub>rss</sub> Reverse Transfer Capacitance		f = 1MHz		35		

### **Functional Characteristics**

Symbol	Parameter	Min	Тур	Max	Unit
G <sub>PS</sub>	$f_1 = 30MHz, f_2 = 30.001MHz, V_{DD} = 50V, I_{DQ} = 250mA, P_{out} = 150W_{PEP}^{-1}$		18		dB
$G_{PS}$	f = 150MHz, V <sub>DD</sub> = 50V, I <sub>DQ</sub> = 250mA, P <sub>out</sub> = 150W	11 dB		иь	
$\eta_{\scriptscriptstyle D}$	$f_1 = 30MHz, f_2 = 30.001MHz, V_{DD} = 50V, I_{DQ} = 250mA, P_{out} = 150W_{PEP}^{-1}$		50		%
IMD <sub>(d3)</sub>	$f_1 = 30MHz, f_2 = 30.001MHz, V_{DD} = 50V, I_{DQ} = 250mA, P_{out} = 150W_{PEP}^{-1}$		-32		dBc
Ψ	$f_1$ = 30MHz, $V_{DD}$ = 50V, $I_{DQ}$ = 250mA, $P_{out}$ = 150W CW 70:1 VSWR - All Phase Angles, 0.2mSec X 20% Duty Factor	No Degradation in Output Power		Power	

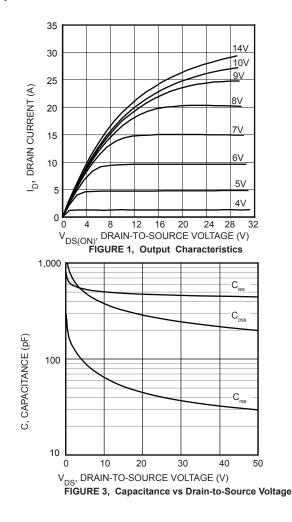
#### **Class A Characteristics**

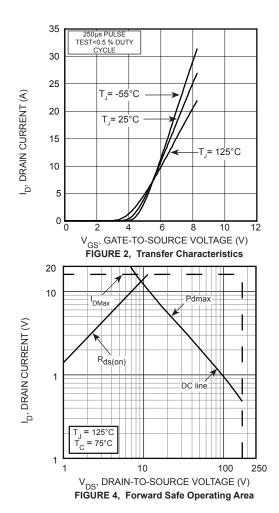
	Symbol	Test Conditions	Min	Тур	Max	Unit
Γ	$G_{PS}$			20		
	$IMD_{(d3)}$	$V_{DD} = 50V$ , $I_{DQ} = 3A$ , $P_{out} = 150W_{PEP}$ , $f1 = 30MHz$ , $f2 = 30.001MHz$		-50		dB
	IMD <sub>(d9-d13)</sub>			-75		

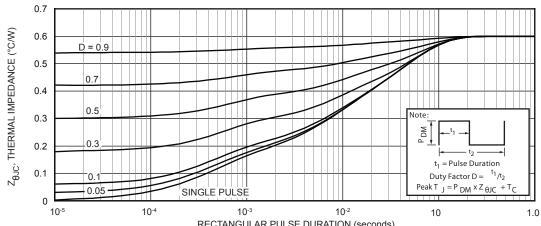
<sup>1.</sup> To MIL-STD-1311 Version A, test method 2204B, Two Tone, Reference Each Tone

Microsemi reserves the right to change, without notice, the specifications and information contained herein.

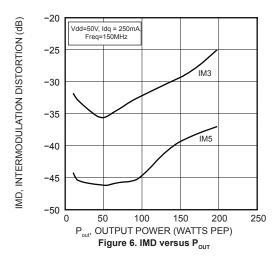
## **Typical Performance Curves**

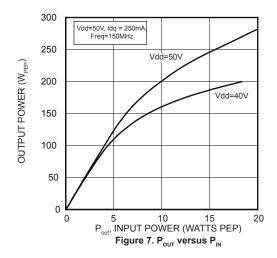




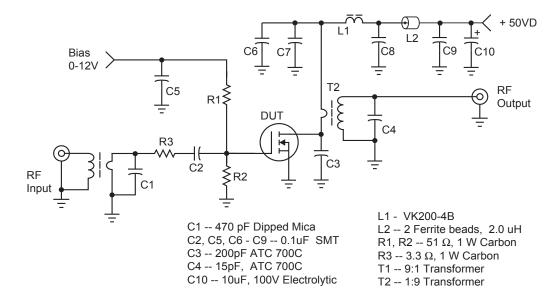


RECTANGULAR PULSE DURATION (seconds)
Figure 5. Maximum Effective Transient Thermal Impedance Junction-to-Case vs Pulse Duration

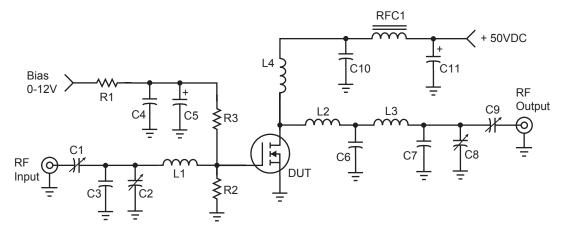




#### 30 MHz test Circuit



#### 150 MHz test Circuit



C1, C2, C8 -- Arco 463 or equivalent

C3 -- 25pF, Unelco

C4 -- 0.1uF, Ceramic

C5 -- 1.0 uF, 15 WV Tantalum C6 -- 250pF, Unelco J101

C7-- 25pF, Unelco J101

C9 -- Arco 262 or equivalent

C10 -- 0.05uF, Ceramic

C11 -- 15uF, 60WV Electrolytic

L1 -- 3/4", #18 into Hairpin

L2 -- Printed Line, 0.200" W x 0.500" L

L3 -- 1", #16 into Hairpin approx 16nH

L4 -- 2 turns #16, 5/16" ID

RFC1 - VK200-4B

R1 -- 150 Ω, 1/2W Carbon

R2 -- 10k Ω, 1/2W Carbon

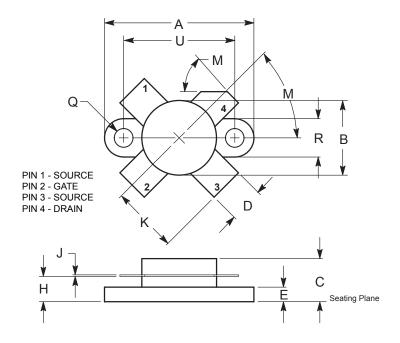
R3 -- 120 Ω, 1/2W Carbon

Adding MP at the end of P/N specifies a matched pair where  $V_{\text{GS(TH)}}$  is matched between the two parts.  $V_{\text{TH}}$  values are marked on the devices per the following table.

Code	Vth Range	Code 2	Vth Range
А	2.900 - 2.975	М	3.650 - 3.725
В	2.975 - 3.050	N	3.725 - 3.800
С	3.050 - 3.125	Р	3.800 - 3.875
D	3.125 - 3.200	R	3.875 - 3.950
Е	3.200 - 3.275	S	3.950 - 4.025
F	3.275 - 3.350	Т	4.025 - 4.100
G	3.350 - 3.425	W	4.100 - 4.175
Н	3.425 - 3.500	Х	4.175 - 4.250
J	3.500 - 3.575	Υ	4.250 - 4.325
K	3.575 - 3.650	Z	4.325 - 4.400

 $<sup>{</sup>m V}_{_{
m TH}}$  values are based on Microsemi measurements at datasheet conditions with an accuracy of 1.0%.

# .5" SOE Package Outline All Dimensions are ± .005



DIM	INCHES		MILLIMETERS			
	MIN	MAX	MIN	MAX		
Α	0.096	0.990	24.39	25.14		
В	0.465	0.510	11.82	12.95		
С	0.229	0.275	5.82	6.98		
D	0.216	0.235	5.49	5.96		
E	0.084	0.110	2.14	2.79		
Н	0.144	0.178	3.66	4.52		
J	0.003	0.007	0.08	0.17		
К	0.435		11.0			
М	45° NOM		45° l	5° NOM		
Q	0.115	0.130	2.93	3.30		
R	0.246	0.255	6.25	6.47		
U	0.720	0.730	18.29	18.54		

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